

Refine Search

Search Results -

Terms	Documents
L27	0

Database:

US Pre-Grant Publication Full-Text Database
 US Patents Full-Text Database
 US OCR Full-Text Database
 EPO Abstracts Database
 JPO Abstracts Database
 Derwent World Patents Index
IBM Technical Disclosure Bulletins

Search:

L28

Search History

DATE: Thursday, January 27, 2005 [Printable Copy](#) [Create Case](#)

<u>Set</u> <u>Name</u>	<u>Query</u>	<u>Hit</u> <u>Count</u>	<u>Set</u> <u>Name</u> result set
side by side			
	DB=TDBD; PLUR=YES; OP=OR		
<u>L28</u>	L27	0	<u>L28</u>
	DB=DWPI; PLUR=YES; OP=OR		
<u>L27</u>	L26	0	<u>L27</u>
	DB=JPAB; PLUR=YES; OP=OR		
<u>L26</u>	L25	0	<u>L26</u>
	DB=EPAB; PLUR=YES; OP=OR		
<u>L25</u>	L24	0	<u>L25</u>
	DB=USOC; PLUR=YES; OP=OR		
<u>L24</u>	L23	0	<u>L24</u>
	DB=USPT; PLUR=YES; OP=OR		
<u>L23</u>	L22	0	<u>L23</u>
	DB=PGPB; PLUR=YES; OP=OR		
<u>L22</u>	L21	0	<u>L22</u>

DB=USPT; PLUR=YES; OP=OR

L21 "double gate CMOS" and "trench gate" 0 L21

L20 "double gate CMOS" 11 L20

L19 6197672 2 L19

L18 5899710 4 L18

L17 L16 0 L17

L16 "trench gate" same (("first gate" near5 (polysilicon)) same ("second gate" near5 (polysilicon))) 0 L16

DB=TDBD; PLUR=YES; OP=OR

L15 L14 0 L15

DB=JPAB; PLUR=YES; OP=OR

L14 L13 0 L14

DB=EPAB; PLUR=YES; OP=OR

L13 L12 0 L13

DB=USOC; PLUR=YES; OP=OR

L12 L11 0 L12

DB=USPT; PLUR=YES; OP=OR

L11 "trench gate" same (("first gate" near5 (N near3 polysilicon)) same ("second gate" near5 (P near3 polysilicon))) 0 L11

L10 "trench gate" same ("first gate" near5 "n type") same ("second gate" near5 "p type") 0 L10

DB=TDBD; PLUR=YES; OP=OR

L9 L8 0 L9

DB=DWPI; PLUR=YES; OP=OR

L8 L7 0 L8

DB=JPAB; PLUR=YES; OP=OR

L7 L6 0 L7

DB=EPAB; PLUR=YES; OP=OR

L6 L5 0 L6

DB=PGPB; PLUR=YES; OP=OR

L5 L4 0 L5

DB=USOC; PLUR=YES; OP=OR

L4 L3 0 L4

DB=USPT; PLUR=YES; OP=OR

L3 L2 and ("first gate" near6 fermi) and ("second gate" near5 fermi) 0 L3

L2 "trench gate" same (multigate or double gate) 1115 L2

L1 6586290 3 L1

END OF SEARCH HISTORY